



查询"NE851M13-T3-A"供应商

NEC's NPN SILICON TRANSISTOR

NE851M13

FEATURES

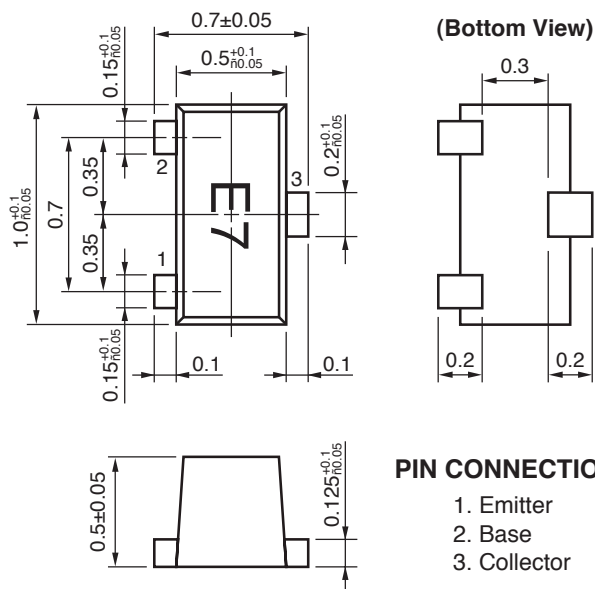
- **NEW MINIATURE M13 PACKAGE:**
 - Small transistor outline
 - 1.0 X 0.5 X 0.5 mm
 - Low profile / 0.50 mm package height
 - Flat lead style for better RF performance
- **IDEAL FOR ≤ 3 GHz OSCILLATORS**
- **LOW PHASE NOISE**
- **LOW PUSHING FACTOR**

DESCRIPTION

NEC's NE851M13 transistor is designed for oscillator applications up to 3 GHz. The NE851M13 features low voltage operation, low phase noise, and high immunity to pushing effects. NEC's new low profile/flat lead style "M13" package is ideal for today's portable wireless applications.

OUTLINE DIMENSIONS (Units in mm)

PACKAGE OUTLINE M13



PIN CONNECTIONS

1. Emitter
2. Base
3. Collector

ELECTRICAL CHARACTERISTICS (TA = 25°C)

PART NUMBER EIAJ ¹ REGISTERED NUMBER PACKAGE OUTLINE		NE851M13 2SC5801 M13			
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
f _T	Gain Bandwidth at V _{CE} = 1 V, I _C = 5 mA, f = 2 GHz	GHz	3.0	4.5	–
	at V _{CE} = 1 V, I _C = 15 mA, f = 2 GHz	GHz	5.0	6.5	–
S ₂₁ ²	Insertion Power Gain at V _{CE} = 1 V, I _C = 5 mA, f = 2 GHz	dB	3.0	4.0	–
	at V _{CE} = 1 V, I _C = 15 mA, f = 2 GHz	dB	4.5	5.5	–
NF	Noise Figure at V _{CE} = 1 V, I _C = 10 mA, f = 2 GHz	dB	–	1.9	2.5
CRE	Reverse Transfer Capacitance ³ at V _{CB} = 0.5 V, I _E = 0 mA, f = 1 MHz	pF	–	0.6	0.8
I _{CBO}	Collector Cutoff Current at V _{CB} = 5 V, I _E = 0	nA	–	–	600
I _{EBO}	Emitter Cutoff Current at V _{EB} = 1 V, I _C = 0	nA	–	–	600
h _{FE}	DC Current Gain ² at V _{CE} = 1 V, I _C = 5 mA		100	120	145

Notes:

1. Electronic Industrial Association of Japan.
2. Pulsed measurement, pulse width ≤ 350 μ s, duty cycle ≤ 2 %.
3. Collector to base capacitance when the emitter is grounded

ABSOLUTE MAXIMUM RATINGS¹ (T_A = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
V _{CB0}	Collector to Base Voltage	V	9
V _{CEO}	Collector to Emitter Voltage	V	5.5
V _{EB0}	Emitter to Base Voltage	V	1.5
I _C	Collector Current	mA	100
P _T ²	Total Power Dissipation	mW	140
T _J	Junction Temperature	°C	150
T _{STG}	Storage Temperature	°C	-65 to +150

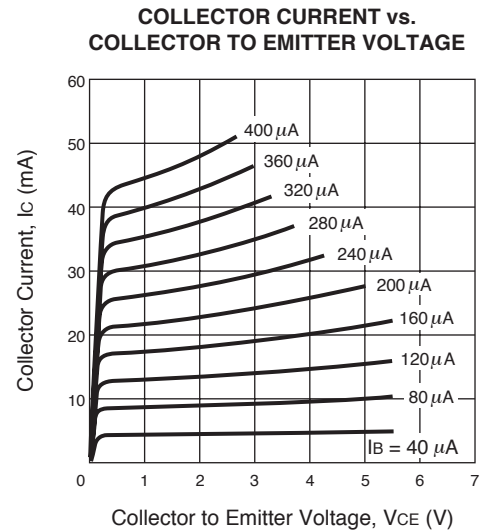
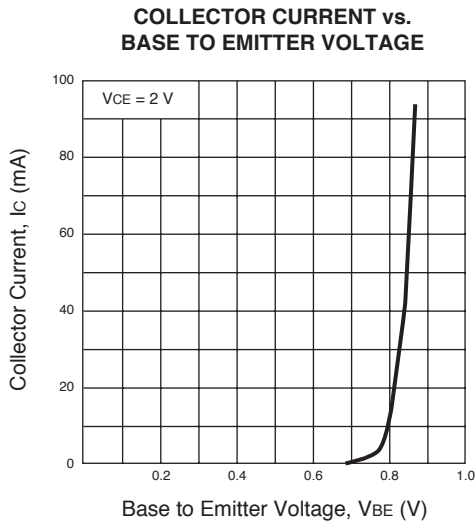
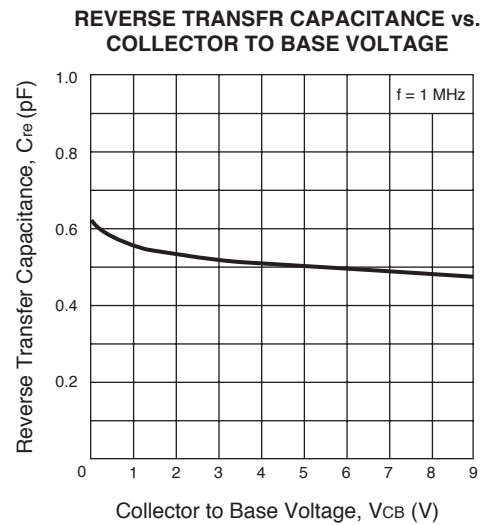
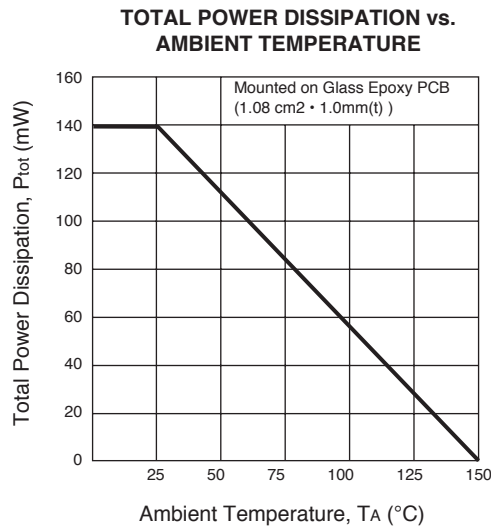
Notes:

1. Operation in excess of any one of these parameters may result in permanent damage.
2. With device mounted on 1.08 cm² X 1.0 mm glass epoxy board.

ORDERING INFORMATION

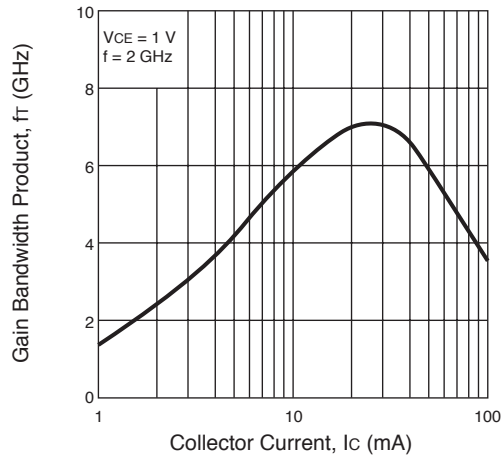
PART NUMBER	QUANTITY
NE851M13-T3-A	10 k pcs./reel

TYPICAL PERFORMANCE CURVES (T_A = 25°C)

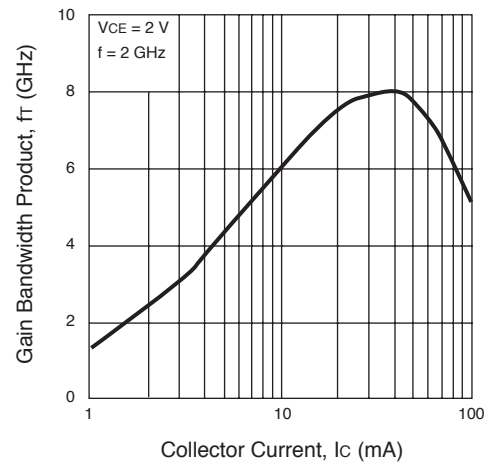


查询"NE851M13-T3-A"供应商
TYPICAL PERFORMANCE CURVES ($T_A = 25^\circ\text{C}$)

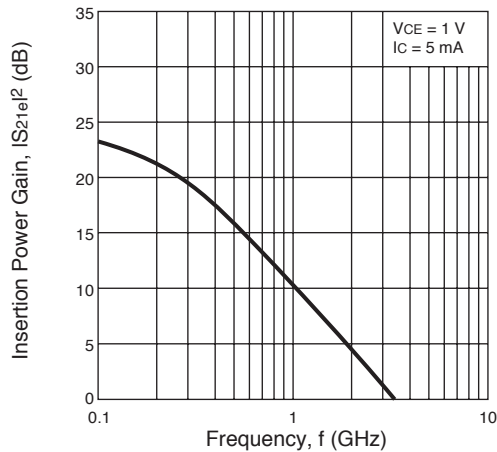
**GAIN BANDWIDTH PRODUCT
vs. COLLECTOR CURRENT**



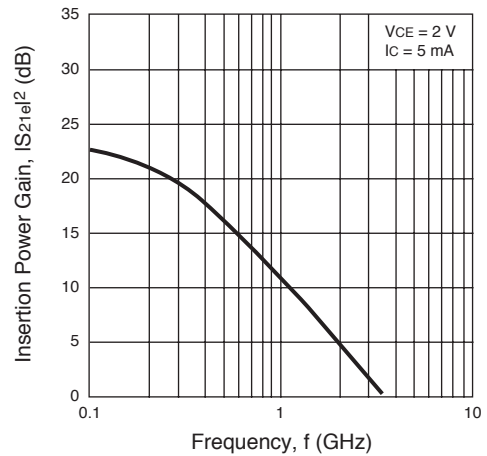
**GAIN BANDWIDTH PRODUCT
vs. COLLECTOR CURRENT**



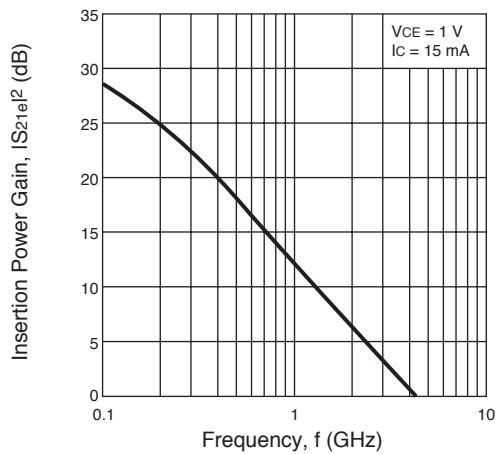
**INSERTION POWER GAIN vs.
FREQUENCY**



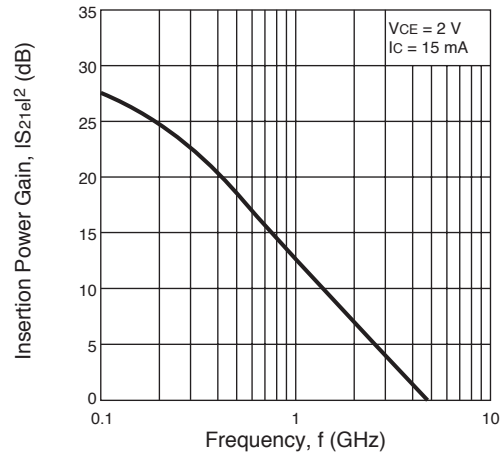
**INSERTION POWER GAIN vs.
FREQUENCY**



**INSERTION POWER GAIN vs.
FREQUENCY**



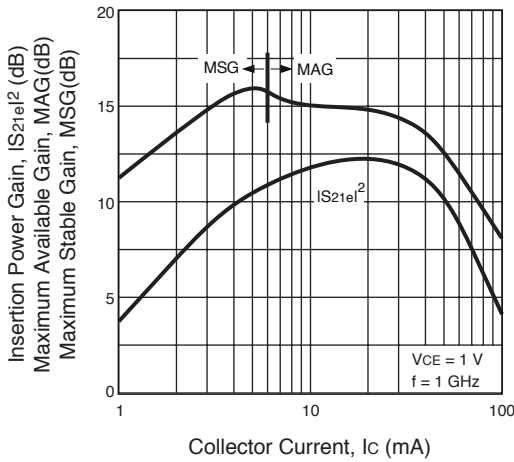
**INSERTION POWER GAIN vs.
FREQUENCY**



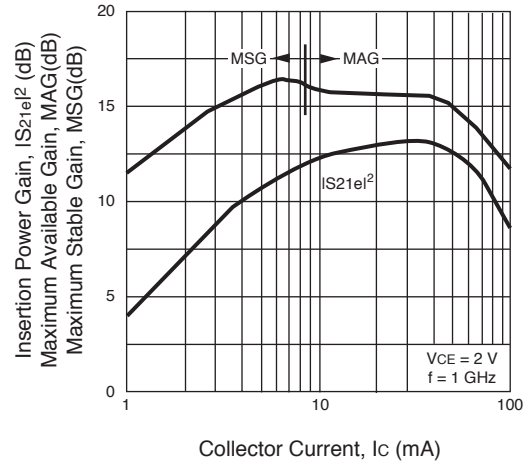
TYPICAL PERFORMANCE CURVES (T_A = 25°C)

NE851M13-13A 代理商

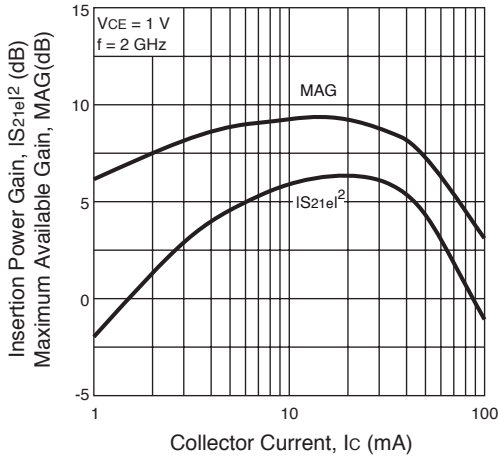
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



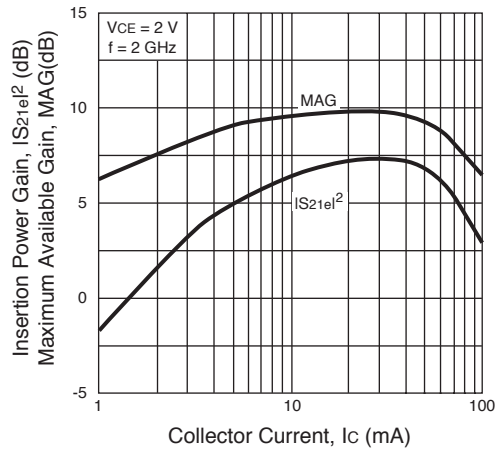
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



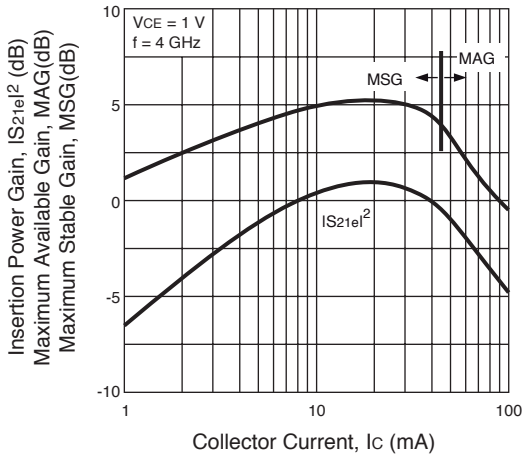
INSERTION POWER GAIN and MAG vs. COLLECTOR CURRENT



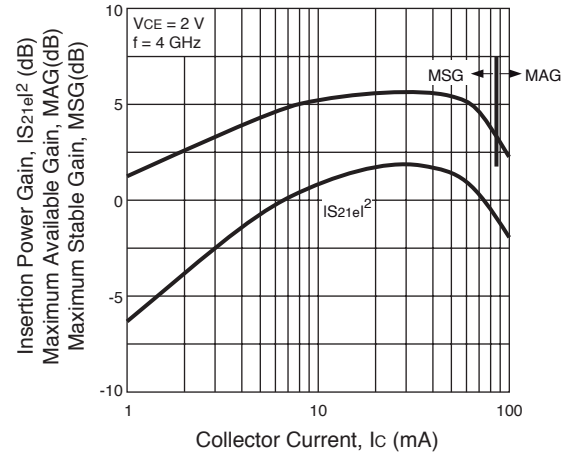
INSERTION POWER GAIN and MAG vs. COLLECTOR CURRENT



INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

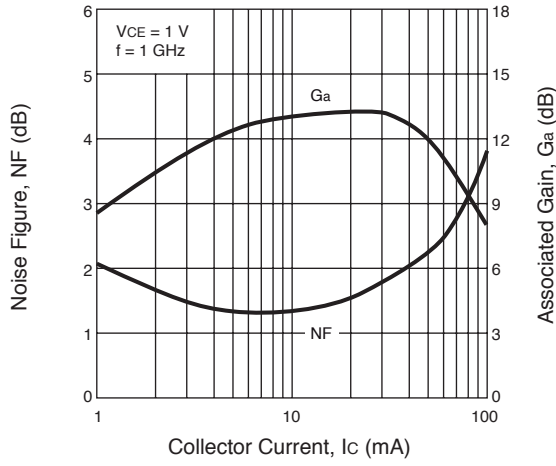


INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

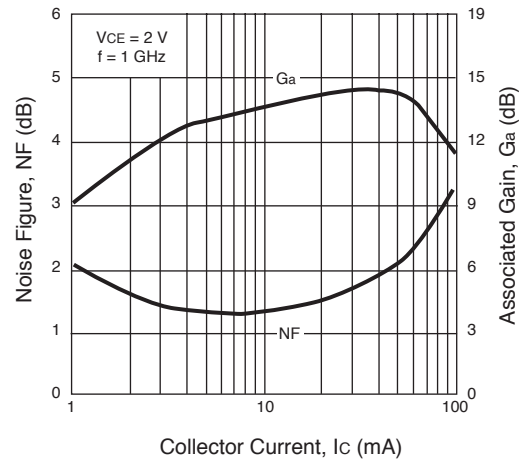


典型性能曲线 (TA = 25°C)

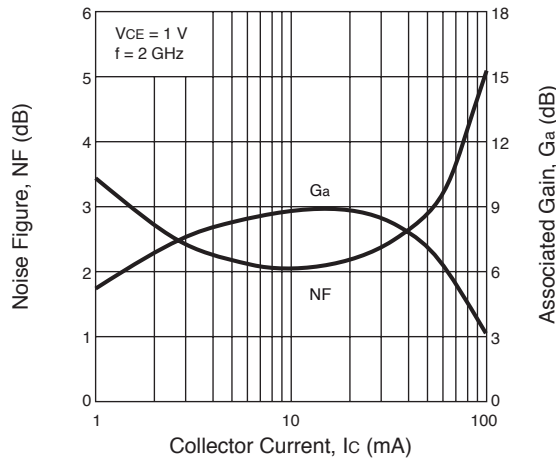
NOISE FIGURE and ASSOCIATED GAIN vs. COLLECTOR CURRENT



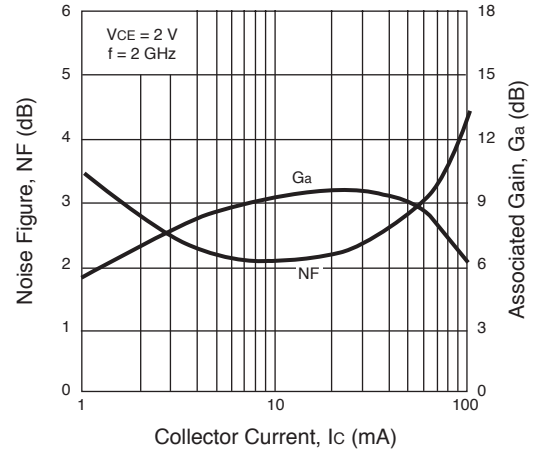
NOISE FIGURE and ASSOCIATED GAIN vs. COLLECTOR CURRENT



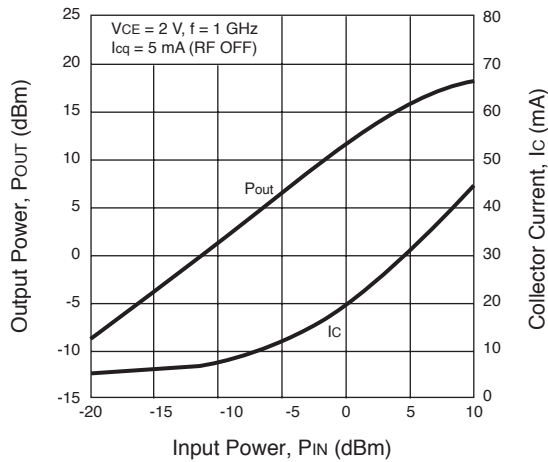
NOISE FIGURE and ASSOCIATED GAIN vs. COLLECTOR CURRENT



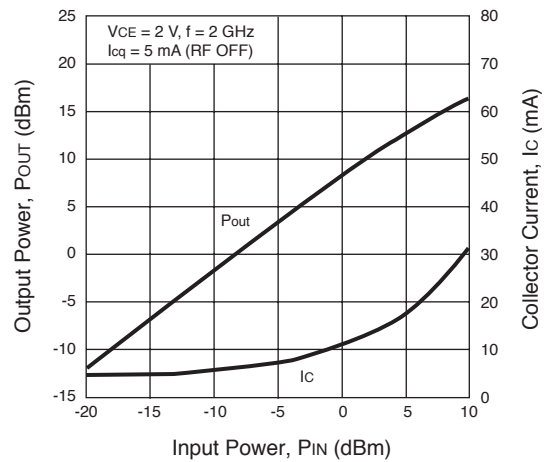
NOISE FIGURE and ASSOCIATED GAIN vs. COLLECTOR CURRENT



OUTPUT POWER AND COLLECTOR CURRENT vs. INPUT POWER

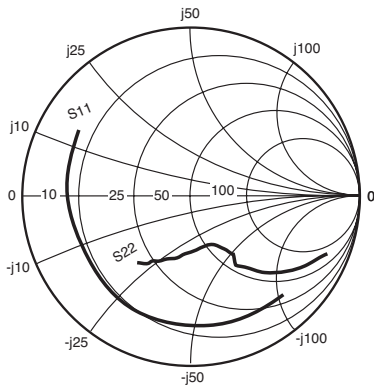


OUTPUT POWER AND COLLECTOR CURRENT vs. INPUT POWER

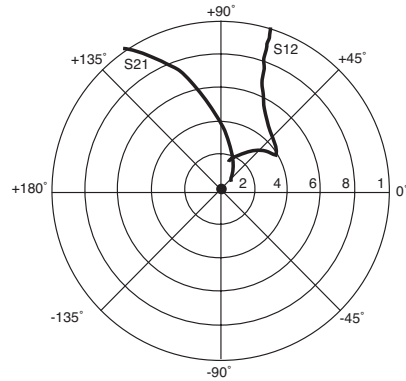


TYPICAL SCATTERING PARAMETERS (TA = 25°C)

[查询 NE851M13-T3-A 供应商](#)



0.100 to 4.000 GHz by 0.050



0.100 to 4.000GHz by 0.050

NE851M13

Vc = 1 V, Ic = 5 mA

FREQUENCY GHz	S11		S21		S12		S22		K	MAG ¹ (dB)
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG		
0.100	0.831	-46.49	13.764	152.54	0.036	66.4	0.901	-23.1	0.068	25.83
0.200	0.789	-81.92	11.335	132.55	0.058	50.3	0.742	-38.6	0.134	22.93
0.300	0.765	-106.07	9.135	118.99	0.069	40.9	0.618	-47.8	0.192	21.23
0.400	0.750	-122.16	7.476	109.52	0.075	35.5	0.533	-53.5	0.250	20.01
0.500	0.706	-133.99	6.157	103.05	0.077	33.0	0.460	-53.3	0.394	19.04
0.600	0.699	-142.06	5.251	97.76	0.078	31.6	0.414	-55.7	0.478	18.26
0.700	0.697	-148.74	4.576	93.13	0.080	31.0	0.382	-58.2	0.551	17.59
0.800	0.696	-153.88	4.062	89.34	0.081	31.4	0.363	-59.5	0.619	17.02
0.900	0.697	-158.33	3.646	85.83	0.082	32.0	0.350	-61.5	0.682	16.51
1.000	0.697	-161.97	3.308	82.71	0.082	33.1	0.339	-63.3	0.751	16.05
1.500	0.704	-174.56	2.262	69.58	0.087	41.9	0.328	-74.5	1.012	13.47
2.000	0.712	176.89	1.721	59.12	0.098	53.1	0.342	-86.9	1.152	10.09
2.500	0.724	169.88	1.391	50.09	0.118	62.5	0.376	-98.8	1.122	8.58
3.000	0.732	163.33	1.166	42.52	0.147	68.6	0.415	-109.4	1.042	7.75
3.500	0.743	156.42	1.002	36.21	0.182	71.3	0.458	-117.8	0.939	7.41
4.000	0.746	150.06	0.879	31.47	0.222	71.8	0.498	-125.3	0.877	5.98

Note:

1. Gain Calculations:

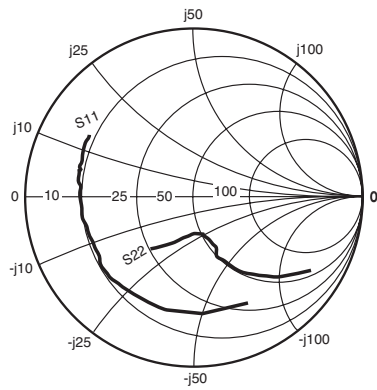
$$MAG = \frac{|S_{21}|}{|S_{12}|} \left(K \pm \sqrt{K^2 - 1} \right). \text{ When } K \leq 1, \text{ MAG is undefined and MSG values are used. } MSG = \frac{|S_{21}|}{|S_{12}|}, K = \frac{1 + |\Delta|^2 - |S_{11}|^2 - |S_{22}|^2}{2 |S_{12} S_{21}|}, \Delta = S_{11} S_{22} - S_{21} S_{12}$$

MAG = Maximum Available Gain

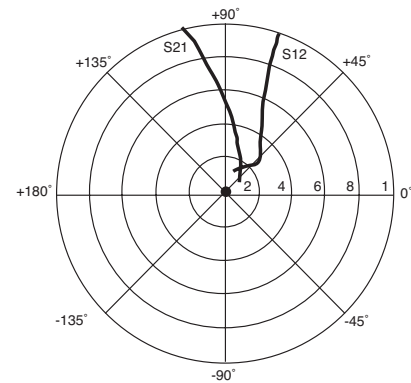
MSG = Maximum Stable Gain

TYPICAL SCATTERING PARAMETERS (T_A = 25°C)

[查询“NE851M13-T3-A”供应商](#)



0.100 to 4.000GHz by 0.050



0.100 to 4.000GHz by 0.050

NE851M13

V_c = 2 V, I_c = 10 mA

FREQUENCY GHz	S ₁₁		S ₂₁		S ₁₂		S ₂₂		K	MAG ¹ (dB)
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG		
0.100	0.718	-62.67	22.758	144.89	0.029	61.8	0.823	-32.5	0.135	28.99
0.200	0.689	-102.19	16.867	123.83	0.042	47.7	0.615	-50.6	0.239	26.05
0.300	0.680	-124.30	12.737	111.69	0.048	42.0	0.486	-60.3	0.334	24.22
0.400	0.677	-137.54	10.068	103.82	0.052	40.1	0.408	-66.1	0.423	22.85
0.500	0.648	-147.55	8.180	98.85	0.055	40.8	0.335	-65.2	0.582	21.74
0.600	0.645	-153.87	6.913	94.59	0.057	41.9	0.296	-67.9	0.679	20.81
0.700	0.647	-158.99	5.980	90.88	0.060	43.5	0.270	-70.9	0.755	19.98
0.800	0.648	-162.97	5.282	87.80	0.063	45.4	0.253	-72.1	0.819	19.23
0.900	0.651	-166.43	4.725	84.93	0.066	47.2	0.243	-74.0	0.871	18.55
1.000	0.652	-169.32	4.275	82.38	0.069	49.2	0.234	-75.8	0.922	17.92
1.500	0.661	-179.34	2.907	71.36	0.087	57.6	0.226	-86.3	1.059	13.75
2.000	0.669	173.47	2.212	62.32	0.109	63.9	0.241	-97.3	1.097	11.18
2.500	0.679	167.37	1.795	54.17	0.135	67.6	0.274	-107.0	1.061	9.73
3.000	0.687	161.58	1.515	47.00	0.164	69.6	0.311	-115.5	1.013	8.96
3.500	0.696	155.30	1.313	40.58	0.197	70.1	0.353	-121.7	0.947	8.24
4.000	0.699	149.56	1.161	35.18	0.232	69.6	0.393	-127.3	0.901	6.99

Note:

1. Gain Calculations:

$$\text{MAG} = \frac{|S_{21}|}{|S_{12}|} \left(K \pm \sqrt{K^2 - 1} \right). \text{ When } K \leq 1, \text{ MAG is undefined and MSG values are used. } \text{MSG} = \frac{|S_{21}|}{|S_{12}|}, K = \frac{1 + |\Delta|^2 - |S_{11}|^2 - |S_{22}|^2}{2 |S_{12}| |S_{21}|}, \Delta = S_{11} S_{22} - S_{21} S_{12}$$

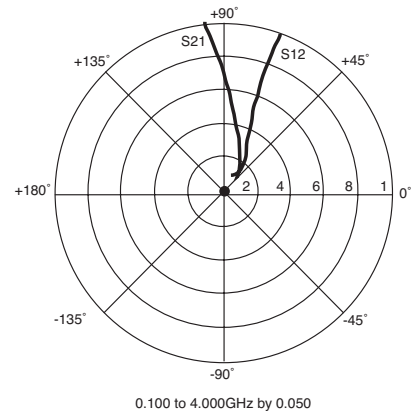
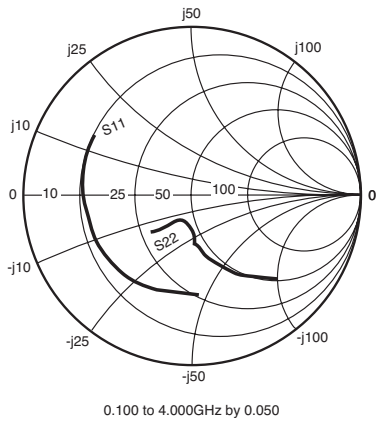
MAG = Maximum Available Gain

MSG = Maximum Stable Gain

NE851M13

TYPICAL SCATTERING PARAMETERS (TA = 25°C)

[查询 NE851M13-T3-A 供应商](#)



NE851M13

Vc = 3 V, Ic = 20 mA

FREQUENCY GHz	S11		S21		S12		S22		K	MAG ¹ (dB)
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG		
0.100	0.592	-86.11	33.025	135.40	0.022	57.5	0.710	-44.7	0.243	31.86
0.200	0.610	-124.37	21.656	115.31	0.031	48.3	0.483	-65.2	0.402	28.50
0.300	0.620	-141.71	15.554	105.23	0.036	47.6	0.370	-75.9	0.532	26.41
0.400	0.626	-151.34	12.032	98.91	0.040	49.1	0.309	-82.6	0.635	24.80
0.500	0.610	-159.31	9.710	95.19	0.044	52.1	0.241	-83.3	0.781	23.47
0.600	0.610	-163.96	8.162	91.77	0.048	54.4	0.212	-87.6	0.862	22.32
0.700	0.613	-167.68	7.032	88.75	0.052	56.5	0.194	-92.2	0.917	21.29
0.800	0.615	-170.58	6.194	86.21	0.057	58.6	0.181	-94.3	0.956	20.36
0.900	0.620	-173.15	5.529	83.82	0.062	60.3	0.173	-96.9	0.983	19.53
1.000	0.621	-175.39	4.996	81.67	0.067	61.8	0.167	-99.4	1.010	18.15
1.500	0.632	176.71	3.387	72.14	0.092	66.6	0.166	-109.9	1.059	14.16
2.000	0.639	170.54	2.578	64.13	0.119	69.0	0.183	-118.5	1.064	11.79
2.500	0.648	165.15	2.096	56.72	0.148	69.7	0.214	-124.5	1.035	10.35
3.000	0.654	159.90	1.775	50.03	0.178	69.5	0.248	-129.5	1.005	9.56
3.500	0.662	154.05	1.546	43.87	0.210	68.7	0.285	-132.5	0.963	8.68
4.000	0.664	148.76	1.376	38.44	0.243	67.5	0.321	-135.5	0.929	7.54

Note:

1. Gain Calculations:

$$\text{MAG} = \frac{|S_{21}|}{|S_{12}|} (K \pm \sqrt{K^2 - 1}). \text{ When } K \leq 1, \text{ MAG is undefined and MSG values are used. } \text{MSG} = \frac{|S_{21}|}{|S_{12}|}, K = \frac{1 + |\Delta|^2 - |S_{11}|^2 - |S_{22}|^2}{2 |S_{12} S_{21}|}, \Delta = S_{11} S_{22} - S_{21} S_{12}$$

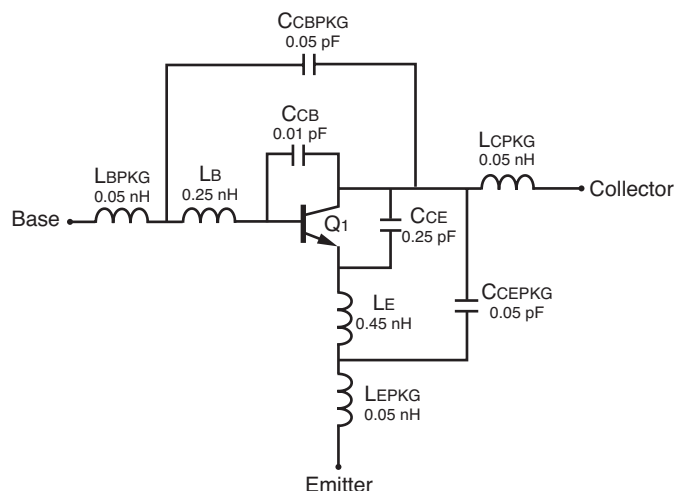
MAG = Maximum Available Gain

MSG = Maximum Stable Gain

NONLINEAR MODEL

[查询"NE851M13 T3-A"供应商](#)

SCHEMATIC



BJT NONLINEAR MODEL PARAMETERS(1)

Parameters	Q1	Parameters	Q1
IS	137e-18	MJC	0.14
BF	166	XCJC	0.5
NF	0.9871	CJS	0
VAF	20.4	VJS	0.75
IKF	50	MJS	0
ISE	80.4e-15	FC	0.55
NE	2.4	TF	15e-12
BR	28.7	XTF	0.1
NR	0.9889	VTF	2
VAR	2.7	ITF	0.03
IKR	0.021	PTF	0
ISC	532e-18	TR	1.0e-9
NC	1.28	EG	1.11
RE	0.45	XTB	0
RB	4	XTI	3
RBM	1	KF	170e-15
IRB	0	AF	1.65
RC	1.7		
CJE	2.4e-12		
VJE	0.87		
MJE	0.34		
CJC	0.65e-12		
VJC	0.52		

(1) Gummel-Poon Model

Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

CEL California Eastern Laboratories, Your source for NEC RF, Microwave, Optoelectronic, and Fiber Optic Semiconductor Devices.

4590 Patrick Henry Drive • Santa Clara, CA 95054-1817 • (408) 988-3500 • FAX (408) 988-0279 • www.cel.com

DATA SUBJECT TO CHANGE WITHOUT NOTICE

ADDITIONAL PARAMETERS

Parameters	NE851M13
CCB	0.01 pF
CCE	0.25 pF
LB	0.25 nH
LE	0.45 nH
CCBPKG	0.05 pF
CCEPKG	0.05 pF
LBX	0.05 nH
LCX	0.05 nH
LEX	0.05 nH

MODEL TEST CONDITIONS

Frequency: 0.1 to 5.0 GHz

Bias: $V_{CE} = 1 \text{ V to } 4 \text{ V}$, $I_C = 1 \text{ mA to } 40 \text{ mA}$

Date: 09/2001

01/27/2003

Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices	
		-A	-AZ
Lead (Pb)	< 1000 PPM	Not Detected	(*)
Mercury	< 1000 PPM	Not Detected	
Cadmium	< 100 PPM	Not Detected	
Hexavalent Chromium	< 1000 PPM	Not Detected	
PBB	< 1000 PPM	Not Detected	
PBDE	< 1000 PPM	Not Detected	

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

Important Information and Disclaimer: Information provided by CEL on its website or in other communications concerning the substance content of its products represents knowledge and belief as of the date that it is provided. CEL bases its knowledge and belief on information provided by third parties and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. CEL has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. CEL and CEL suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.